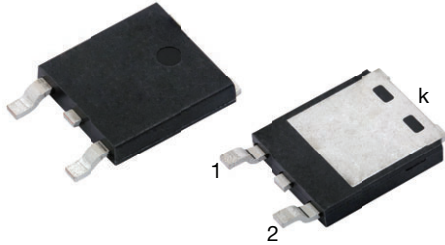
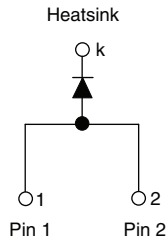


## Ultralow $V_F$ Ultrafast Rectifier, 6 A FRED Pt<sup>®</sup>

 eSMP<sup>®</sup> Series


SlimDPAK (TO-252AE)



### FEATURES

- Ultrafast recovery time, extremely low  $V_F$  and soft recovery
- For PFC CCM operation
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
  - Automotive ordering code: base P/NHM3, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

AUTOMOTIVE GRADE


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

PRODUCT SUMMARY	
Package	SlimDPAK (TO-252AE)
$I_{F(AV)}$	6 A
$V_R$	600 V
$V_F$ at $I_F$	0.98 V
$t_{rr}$ (typ.)	34 ns
$T_J$ max.	175 °C
Diode variation	Single

### TYPICAL APPLICATIONS

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### MECHANICAL DATA

**Case:** SlimDPAK

Molding compound meets UL 94 V-0 flammability rating

Base PN/HM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 158\text{ °C}$	6	A
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25\text{ °C}$	80	
Operating junction and storage temperatures	$T_J, T_{Stg}$		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100\ \mu\text{A}$	600	-	-	V
		$I_F = 6\ \text{A}$	-	1.15	1.35	
Forward voltage	$V_F$	$I_F = 6\ \text{A}, T_J = 150\text{ °C}$	-	0.98	1.15	
		$V_R = V_R$ rated	-	-	5	
Reverse leakage current	$I_R$	$T_J = 150\text{ °C}, V_R = V_R$ rated	-	-	125	
			-	10	-	pF
Junction capacitance	$C_T$	$V_R = 600\ \text{V}$	-	10	-	

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1\text{ A}$ , $dI_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	45	-	ns
		$I_F = 1\text{ A}$ , $dI_F/dt = 100\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	34	-	
		$I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{RR} = 0.25\text{ A}$	-	-	50	
		$T_J = 25\text{ }^\circ\text{C}$	-	65	-	
		$T_J = 125\text{ }^\circ\text{C}$	-	90	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$	-	9.5	-	A
		$T_J = 125\text{ }^\circ\text{C}$	-	13.5	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	-	320	-	nC
		$T_J = 125\text{ }^\circ\text{C}$	-	620	-	

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	175	$^\circ\text{C}$
Thermal resistance, junction to case	$R_{thJC}$		-	-	2.5	$^\circ\text{C}/\text{W}$
Marking device		Case style SlimDPAK (TO-252AE)	6EVL06			

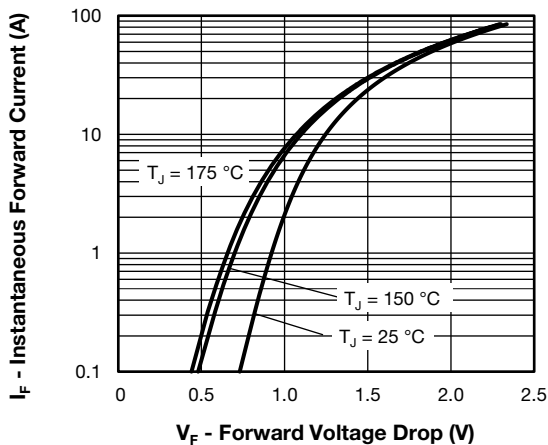


Fig. 1 - Typical Forward Voltage Drop Characteristics

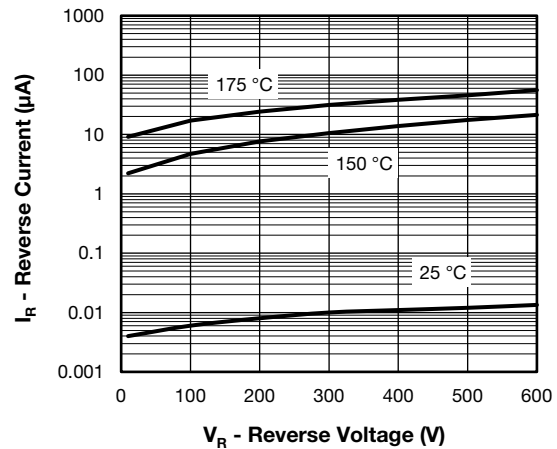


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

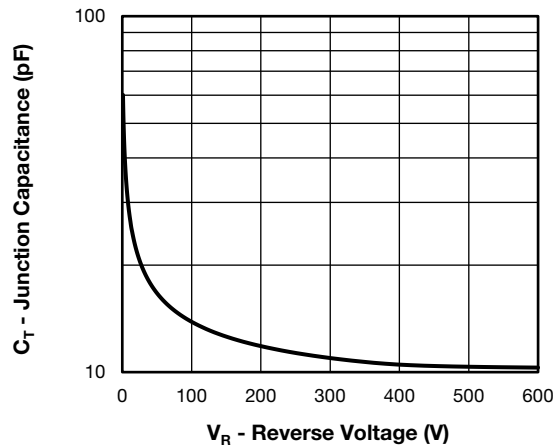


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

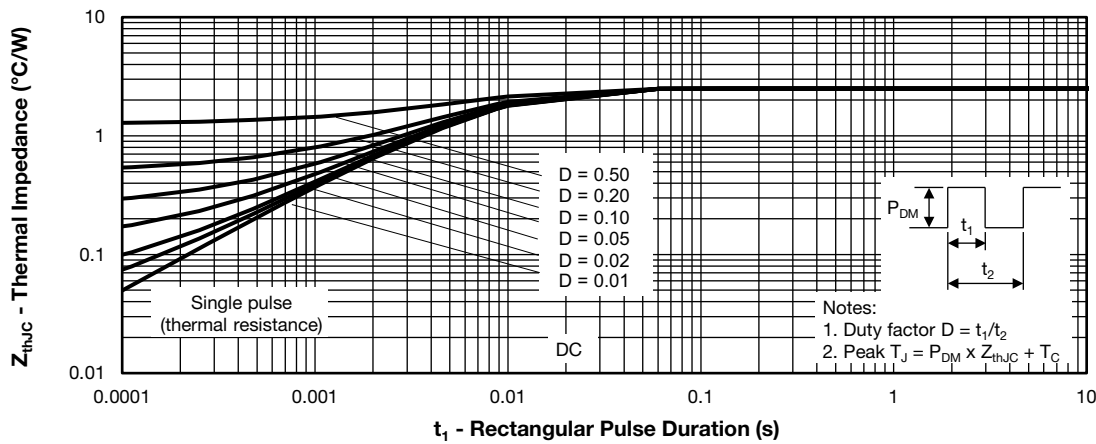


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

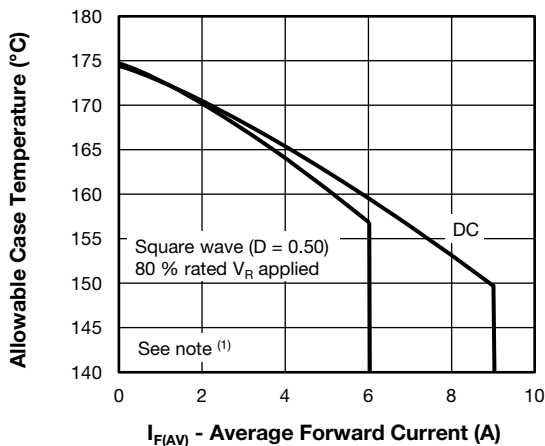


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

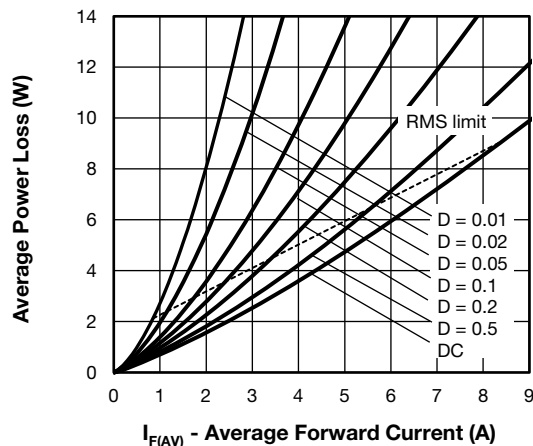
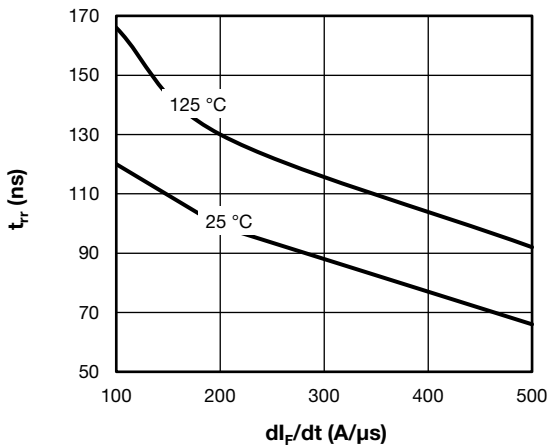
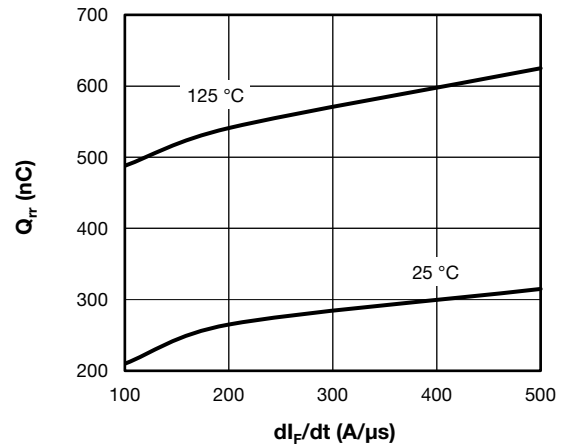
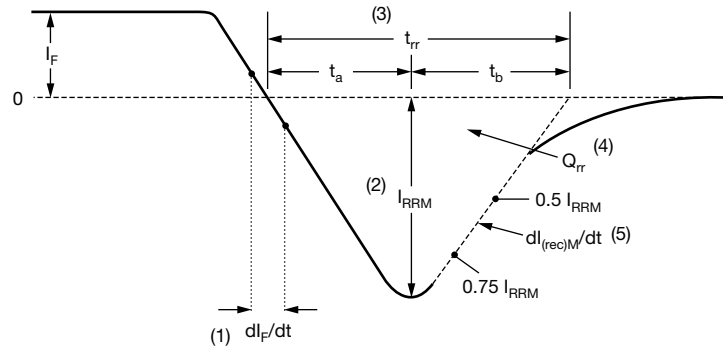


Fig. 6 - Forward Power Loss Characteristics

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$


 Fig. 7 - Typical Reverse Recovery Time vs.  $di_F/dt$ 

 Fig. 8 - Typical Stored Charge vs.  $di_F/dt$ 


- (1)  $di_F/dt$  - rate of change of current through zero crossing
- (2)  $I_{RRM}$  - peak reverse recovery current
- (3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.

- (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$

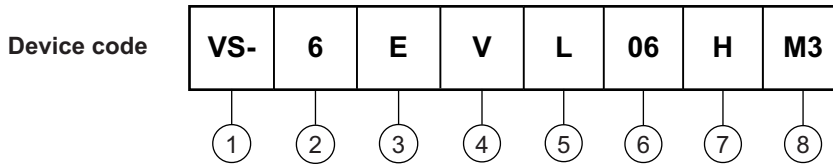
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

- (5)  $dl_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating (6 = 6 A)
- 3** - Circuit configuration:  
E = single die
- 4** - V = SlimDPAK
- 5** - Process type:  
L = ultralow  $V_F$  ultrafast rectifier
- 6** - Voltage code (06 = 600 V)
- 7** - H = AEC-Q101 qualified
- 8** - Environmental digit:  
M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

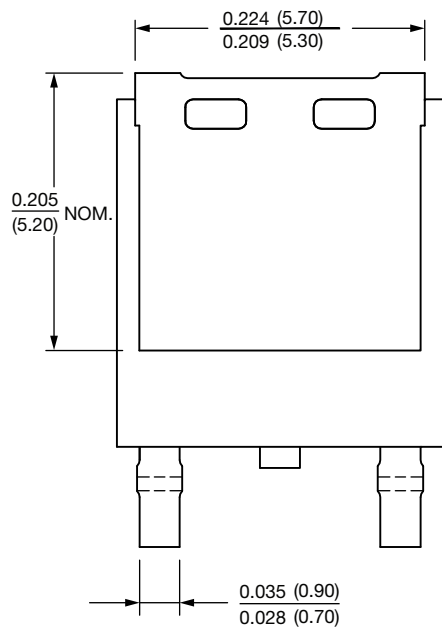
ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION
VS-6EVL06HM3/I	0.20	1	4500	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?96081">www.vishay.com/doc?96081</a>
Part marking information	<a href="http://www.vishay.com/doc?96085">www.vishay.com/doc?96085</a>
Packaging information	<a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a>



## SlimDPAK

**DIMENSIONS** in inches (millimeters)





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- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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